

April 2002 Revised August 2003

74LCXH32245

Low Voltage 32-Bit Bidirectional Transceiver with 5V Tolerant Inputs and Outputs with Bushold

General Description

The LCXH32245 contains thirty-two non-inverting bidirectional buffers with 3-STATE outputs and is intended for bus oriented applications. The device is designed for low voltage (2.5V or 3.3V) $V_{\rm CC}$ applications with capability of interfacing to a 5V signal environment. The device is byte controlled. Each byte has separate control inputs which could be shorted together for full 32-bit operation. The T/\overline{R} inputs determine the direction of data flow through the device. The $\overline{\rm OE}$ inputs disable both the A and B ports by placing them in a high impedance state.

The LCXH32245 data inputs include bushold, eliminating the need for external pull-up/down resistors to hold unused inputs

The LCXH32245 is fabricated with an advanced CMOS technology to achieve high speed operation while maintaining CMOS low power dissipation.

Features

- 5V tolerant inputs and outputs
- 2.3V to 3.6V V_{CC} specifications provided
- 4.5 ns t_{PD} max ($V_{CC} = 3.3V$), 20 μ A I_{CC} max
- Power-off high impedance inputs and outputs
- Bushold on inputs eliminates the need for external pull-up/down resistors
- Supports live insertion/withdrawal (Note 1)
- \blacksquare ±24 mA output drive (V_{CC} = 3.0V)
- Uses patented noise/EMI reduction circuitry
- Latch-up performance exceeds 500 mA
- ESD performance:

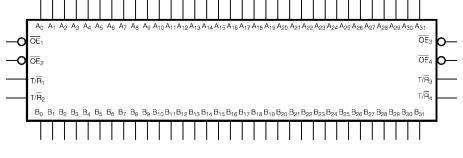
Human body model > 2000V Machine model > 200V

■ Packaged in plastic Fine-Pitch Ball Grid Array (FBGA)

Note 1: To ensure the high-impedance state during power-up or down, OE should be tied to VCC through a pull-up resistor: the minimum value or the resistor is determined by the current-sourcing capability of the driver.

Ordering Code:

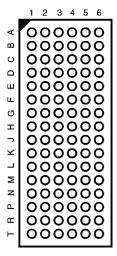
| Order Number | Package Number | Package Description | | | | |
|-----------------------------------|----------------------------|--|--|--|--|--|
| 74LCXH32245G (Note 2) (Note 3) | BGA96A | 96-Ball Fine-Pitch Ball Grid Array (FBGA), JEDEC MO-205, 5.5mm Wide | | | | |
| Note 2: Ordering Code | • | Constitute and the state of the | | | | |
| Note 3: Devices also a | ivaliable in Tape and Reel | Specify by appending the suffix letter "X" to the ordering code. | | | | |
| Logic Sym | bol | | | | | |
| ı | | | | | | |



© 2003 Fairchild Semiconductor Corporation

DS500727

Connection Diagram



(Top Thru View)

Pin Descriptions

| Pin Names | Description |
|---------------------------------|----------------------------------|
| OE _n | Output Enable Input (Active LOW) |
| T/\overline{R}_n | Transmit/Receive Input |
| A ₀ -A ₃₁ | Side A Inputs/3-STATE Outputs |
| B ₀ -B ₃₁ | Side B Inputs/3-STATE Outputs |

FBGA Pin Assignments

| | 1 | 2 | 3 | 4 | 5 | 6 |
|---|-----------------|-----------------|--------------------|------------------|-----------------|-----------------|
| Α | B ₁ | B ₀ | T/R ₁ | ŌE ₁ | A ₀ | A ₁ |
| В | В ₃ | B ₂ | GND | GND | A ₂ | A ₃ |
| С | B ₅ | B ₄ | V _{CC1} | V _{CC1} | A ₄ | A ₅ |
| D | B ₇ | B ₆ | GND | GND | A ₆ | A ₇ |
| Е | B ₉ | B ₈ | GND | GND | A ₈ | A ₉ |
| F | B ₁₁ | B ₁₀ | V _{CC1} | V _{CC1} | A ₁₀ | A ₁₁ |
| G | B ₁₃ | B ₁₂ | GND | GND | A ₁₂ | A ₁₃ |
| Н | B ₁₄ | B ₁₅ | T/\overline{R}_2 | OE ₂ | A ₁₅ | A ₁₄ |
| J | B ₁₇ | B ₁₆ | T/R ₃ | ŌE ₃ | A ₁₆ | A ₁₇ |
| K | B ₁₉ | B ₁₈ | GND | GND | A ₁₈ | A ₁₉ |
| L | B ₂₁ | B ₂₀ | V_{CC2} | V_{CC2} | A ₂₀ | A ₂₁ |
| М | B ₂₃ | B ₂₂ | GND | GND | A ₂₂ | A ₂₃ |
| N | B ₂₅ | B ₂₄ | GND | GND | A ₂₄ | A ₂₅ |
| Р | B ₂₇ | B ₂₆ | V_{CC2} | V_{CC2} | A ₂₆ | A ₂₇ |
| R | B ₂₉ | B ₂₈ | GND | GND | A ₂₈ | A ₂₉ |
| Т | B ₃₀ | B ₃₁ | T/R ₄ | ŌE ₄ | A ₃₁ | A ₃₀ |

Truth Tables

| Inp | uts | Outputs | | |
|-----------------|------------------|--|--|--|
| OE ₁ | T/R ₁ | | | |
| L | L | Bus B ₀ –B ₇ Data to Bus A ₀ –A ₇ | | |
| L | Н | Bus A ₀ –A ₇ Data to Bus B ₀ –B ₇ | | |
| Н | Х | HIGH–Z State on A ₀ –A ₇ ,B ₀ –B ₇ | | |

| Inp | uts | Outputo | | |
|-----------------|------------------|--|--|--|
| OE ₂ | T/R ₂ | Outputs | | |
| L | L | Bus B ₈ -B ₁₅ Data to Bus A ₈ -A ₁₅ | | |
| L | Н | Bus A ₈ -A ₁₅ Data to Bus B ₈ -B ₁₅ | | |
| Н | Х | HIGH–Z State on A ₈ –A ₁₅ ,B ₈ –B ₁₅ | | |

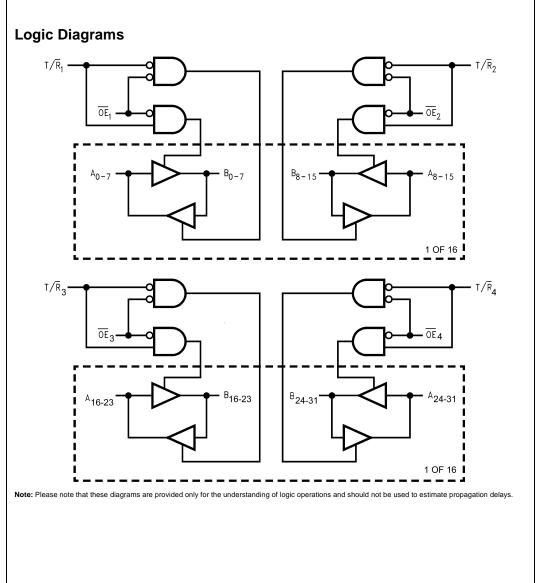
H = HIGH Voltage Level

| Inp | uts | Outpute | | | |
|-----------------|------------------|--|--|--|--|
| OE ₃ | T/R ₃ | Outputs | | | |
| L | L | Bus B ₁₆ –B ₂₃ Data to Bus A ₁₆ –A ₂₃ | | | |
| L | Н | Bus A ₁₆ -A ₂₃ Data to Bus B ₁₆ -B ₂₃ | | | |
| Н | Х | HIGH-Z State on A ₁₆ -A ₂₃ ,B ₁₆ -B ₂₃ | | | |

| Inp | uts | Outputo | |
|-----------------|------------------|--|--|
| OE ₄ | T/R ₄ | Outputs | |
| L L | | Bus B ₂₄ –B ₃₁ Data to Bus A ₂₄ –A ₃₁ | |
| L | Н | Bus B ₂₄ –A ₃₁ Data to Bus B ₂₄ –B ₃₁ | |
| Н | Х | HIGH–Z State on A ₂₄ –A ₃₁ ,B ₂₄ –B ₃₁ | |

L = LOW Voltage Level X = Immaterial

Z = High Impedance



Absolute Maximum Ratings(Note 4)

| Symbol | Parameter | Value | Conditions | Units | |
|------------------|----------------------------------|--------------------------|--------------------------------------|-------|--|
| V _{CC} | Supply Voltage | −0.5 to +7.0 | | V | |
| V _I | T/R, OE | -0.5 to +7.0 | | V | |
| | I/O Ports | -0.5 to $V_{CC} + 0.5$ | | v | |
| Vo | DC Output Voltage | −0.5 to +7.0 | Output in 3-STATE | V | |
| | | -0.5 to $V_{CC} + 0.5$ | Output in HIGH or LOW State (Note 5) | | |
| I _{IK} | DC Input Diode Current | -50 | V _I < GND | mA | |
| I _{OK} | DC Output Diode Current | -50 | V _O < GND | mA | |
| | | +50 | $V_O > V_{CC}$ | 111/4 | |
| Io | DC Output Source/Sink Current | ±50 | | mA | |
| I _{CC} | DC Supply Current per Supply Pin | ±100 | | mA | |
| I _{GND} | DC Ground Current per Ground Pin | ±100 | | mA | |
| T _{STG} | Storage Temperature | -65 to +150 | | °C | |

Recommended Operating Conditions (Note 6)

| Symbol | Parameter | | Min | Max | Units |
|----------------------------------|--|--|-----|-----------------|-------|
| V _{CC} | Supply Voltage | Operating | 2.0 | 3.6 | V |
| | | 1.5 | 3.6 | v | |
| VI | Input Voltage | | 0 | V _{CC} | V |
| Vo | Output Voltage | HIGH or LOW State | 0 | V_{CC} | V |
| | | 3-STATE | 0 | 5.5 | v |
| I _{OH} /I _{OL} | Output Current | $V_{CC} = 3.0V - 3.6V$ | | ±24 | |
| | | $V_{CC} = 3.0V - 3.6V$ $V_{CC} = 2.7V - 3.0V$ $V_{CC} = 2.3V - 2.7V$ | | ±12 | mA |
| | | $V_{CC} = 2.3V - 2.7V$ | | ±8 | |
| T _A | Free-Air Operating Temperature | | -40 | 85 | °C |
| Δt/ΔV | Input Edge Rate, V _{IN} = 0.8V–2.0V, V _{CC} = 3.0V | | 0 | 10 | ns/V |

Note 4: The Absolute Maximum Ratings are those values beyond which the safety of the device cannot be guaranteed. The device should not be operated at these limits. The parametric values defined in the Electrical Characteristics tables are not guaranteed at the Absolute Maximum Ratings. The "Recommended Operating Conditions" table will define the conditions for actual device operation.

DC Electrical Characteristics

| Symbol | Parameter | Conditions | V _{CC} | $T_A = -40^{\circ}C \text{ to } +85^{\circ}C$ | | Units |
|-----------------|---------------------------|--------------------------|-----------------|---|------|-------|
| Oymboi | i arameter | Conditions | (V) | Min | Max | Onito |
| V _{IH} | HIGH Level Input Voltage | | 2.3 – 2.7 | 1.7 | | V |
| | | | 2.7 – 3.6 | 2.0 | | v |
| V _{IL} | LOW Level Input Voltage | | 2.3 – 2.7 | | 0.7 | V |
| | | | 2.7 – 3.6 | | 8.0 | v |
| V _{OH} | HIGH Level Output Voltage | $I_{OH} = -100 \mu A$ | 2.3 – 3.6 | V _{CC} - 0.2 | | |
| | | I _{OH} = -8 mA | 2.3 | 1.8 | | |
| | | I _{OH} = -12 mA | 2.7 | 2.2 | | V |
| | | I _{OH} = -18 mA | 3.0 | 2.4 | | |
| | | I _{OH} = -24 mA | 3.0 | 2.2 | | |
| V _{OL} | LOW Level Output Voltage | $I_{OL} = 100 \mu A$ | 2.3 – 3.6 | | 0.2 | |
| | | I _{OL} = 8 mA | 2.3 | | 0.6 | |
| | | I _{OL} = 12 mA | 2.7 | | 0.4 | V |
| | | I _{OL} = 16 mA | 3.0 | | 0.4 | |
| | | $I_{OL} = 24 \text{ mA}$ | 3.0 | | 0.55 | |

Note 5: I_O Absolute Maximum Rating must be observed.

Note 6: Floating or unused control inputs must be HIGH or LOW.

DC Electrical Characteristics (Continued)

| Symbol | Parameter | Conditions | V _{cc} | $T_A = -40^{\circ}C \text{ to } +85^{\circ}C$ | | Units |
|----------------------|---------------------------------------|---|-----------------|---|------|--------|
| Symbol | | Conditions | (V) | Min | Max | Ullits |
| I | Input Leakage Current | 0 ≤ V ₁ ≤ 5.5V | 2.3 – 3.6 | | ±5.0 | |
| I _{I(HOLD)} | Bushold Input Minimum | V _{IN} = 0.7V | 2.3 | 45 | | |
| | Drive Hold Current | V _{IN} = 1.7V | 2.3 | -45 | | μΑ |
| | | V _{IN} = 0.8V | 3.0 | 75 | | |
| | | V _{IN} = 2.0V | 3.0 | -75 | | Ï |
| I _{I(OD)} | Bushold Input Over-Drive | (Note 7) | 2.7 | 300 | | μΑ |
| | Current to Change State | (Note 8) | 2.1 | -300 | | |
| | | (Note 7) | 3.6 | 450 | | |
| | | (Note 8) | 3.0 | -450 | | |
| I _{OZ} | 3-STATE I/O Leakage | 0 ≤ V _O ≤ 5.5V | 2.3 – 3.6 | | ±5.0 | μА |
| | | $V_I = V_{IH}$ or V_{IL} | 2.5 – 3.0 | | ±3.0 | μΛ |
| I _{OFF} | Power-Off Leakage Current | V_I or $V_O = 5.5V$ | 0 | | 10 | μΑ |
| I _{CC} | Quiescent Supply Current | $V_I = V_{CC}$ or GND | 2.3–3.6 | | 20 | μА |
| | | $3.6V \le V_I, V_O \le 5.5V \text{ (Note 9)}$ | 2.3–3.6 | | ±20 | μΑ |
| ΔI_{CC} | Increase in I _{CC} per Input | $V_{IH} = V_{CC} - 0.6V$ | 2.3–3.6 | | 500 | μΑ |

Note 7: An external driver must source at least the specified current to switch from LOW-to-HIGH.

AC Electrical Characteristics

| | | $T_A = -40$ °C to $+85$ °C, $R_L = 500\Omega$ | | | | | | |
|------------------|--|---|-----------|---------------------------|-----|--------------------------|-----|-------|
| Symbol | Parameter | V _{CC} = 3.3 | 3V ± 0.3V | $V \pm 0.3V$ $V_{CC} = 3$ | | $V_{CC} = 2.5V \pm 0.2V$ | | Units |
| Syllibol | | C _L = 50 pF | | C _L = 50 pF | | C _L = 30 pF | | Units |
| | | Min | Max | Min | Max | Min | Max | |
| t _{PHL} | Propagation Delay | 1.0 | 4.5 | 1.0 | 5.2 | 1.0 | 5.4 | ns |
| t _{PLH} | A _n to B _n or B _n to A _n | 1.0 | 4.5 | 1.0 | 5.2 | 1.0 | 5.4 | 115 |
| t _{PZL} | Output Enable Time | 1.0 | 6.5 | 1.0 | 7.2 | 1.0 | 8.5 | ns |
| t _{PZH} | | 1.0 | 6.5 | 1.0 | 7.2 | 1.0 | 8.5 | 115 |
| t _{PLZ} | Output Disable Time | 1.0 | 6.4 | 1.0 | 6.9 | 1.0 | 7.7 | ns |
| t _{PHZ} | | 1.0 | 6.4 | 1.0 | 6.9 | 1.0 | 7.7 | 113 |

Dynamic Switching Characteristics

| Symbol | Parameter | Conditions | V _{cc} | $T_A = 25^{\circ}C$ | Units |
|------------------|---|---|-----------------|---------------------|-------|
| | | | (V) | Typical | |
| V _{OLP} | Quiet Output Dynamic Peak V _{OL} | $C_L = 50 \text{ pF}, V_{IH} = 3.3 \text{V}, V_{IL} = 0 \text{V}$ | 3.3 | 0.8 | V |
| | | $C_L = 30 \text{ pF}, V_{IH} = 2.5 \text{V}, V_{IL} = 0 \text{V}$ | 2.5 | 0.6 | V |
| V _{OLV} | Quiet Output Dynamic Valley V _{OL} | $C_L = 50 \text{ pF}, V_{IH} = 3.3 \text{V}, V_{IL} = 0 \text{V}$ | 3.3 | -0.8 | W |
| | | $C_L = 30 \text{ pF}, V_{IH} = 2.5 \text{V}, V_{IL} = 0 \text{V}$ | 2.5 | -0.6 | V |

Capacitance

| Symbol | Parameter | Conditions | Typical | Units |
|------------------|-------------------------------|---|---------|-------|
| C _{IN} | Input Capacitance | $V_{CC} = Open, V_I = 0V \text{ or } V_{CC}$ | 7 | pF |
| C _{I/O} | Input/Output Capacitance | $V_{CC} = 3.3V$, $V_I = 0V$ or V_{CC} | 8 | pF |
| C _{PD} | Power Dissipation Capacitance | $V_{CC} = 3.3V$, $V_{I} = 0V$ or V_{CC} , $f = 10$ MHz | 20 | pF |

Note 8: An external driver must sink at least the specified current to switch from HIGH-to-LOW.

Note 9: Outputs disabled or 3-STATE only.

AC LOADING and WAVEFORMS Generic for LCX Family

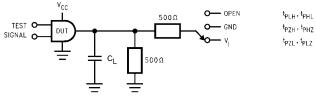
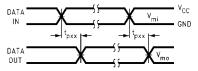
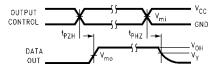


FIGURE 1. AC Test Circuit (C_L includes probe and jig capacitance)

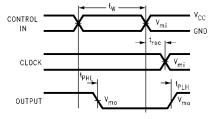
| Test | Switch | |
|-------------------------------------|--|--|
| t _{PLH} , t _{PHL} | Open | |
| t _{PZL} , t _{PLZ} | 6V at V $_{CC}$ = 3.3 \pm 0.3V, and 2.7V V $_{CC}$ x 2 at V $_{CC}$ = 2.5 \pm 0.2V | |
| t _{PZH} , t _{PHZ} | GND | |



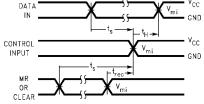
Waveform for Inverting and Non-Inverting Functions



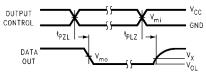
3-STATE Output High Enable and Disable Times for Logic



Propagation Delay. Pulse Width and \mathbf{t}_{rec} Waveforms



Setup Time, Hold Time and Recovery Time for Logic



3-STATE Output Low Enable and Disable Times for Logic

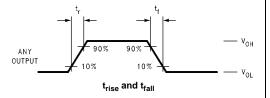
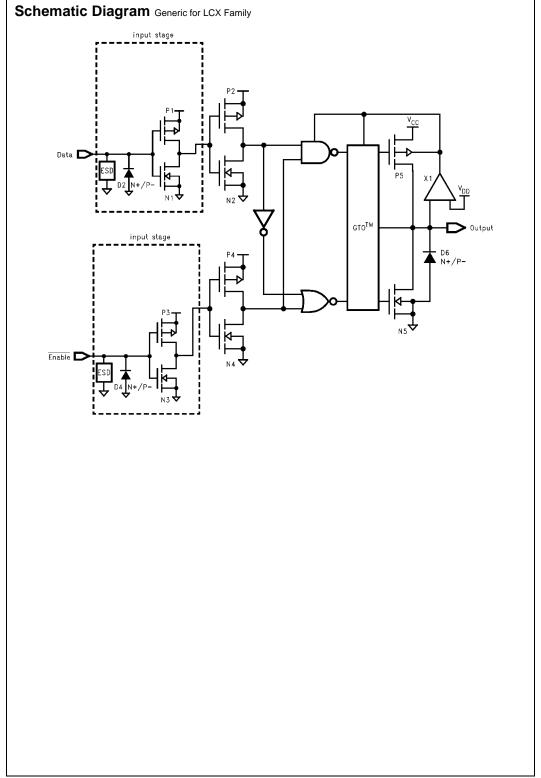
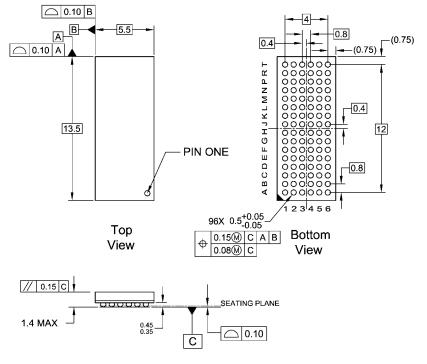


FIGURE 2. Waveforms (Input Characteristics; f =1MHz, $t_r = t_f = 3ns$)

| Symbol | V _{cc} | | | |
|-----------------|------------------------|------------------------|-------------------------|--|
| Cymber | $3.3V \pm 0.3V$ | 2.7V | 2.5V ± 0.2V | |
| V _{mi} | 1.5V | 1.5V | V _{CC} /2 | |
| V _{mo} | 1.5V | 1.5V | V _{CC} /2 | |
| V _x | $V_{OL} + 0.3V$ | V _{OL} + 0.3V | V _{OL} + 0.15V | |
| V _y | V _{OH} – 0.3V | V _{OH} – 0.3V | V _{OH} – 0.15V | |



Physical Dimensions inches (millimeters) unless otherwise noted



NOTES:

- A. THIS PACKAGE CONFORMS TO JEDEC M0-205
- B. ALL DIMENSIONS IN MILLIMETERS
- C. LAND PATTERN RECOMMENDATION: NSMD (Non Solder Mask Defined)
 .35MM DIA PADS WITH A SOLDERMASK OPENING OF .45MM CONCENTRIC TO PADS
 D. DRAWING CONFORMS TO ASME Y14.5M-1994

BGA96ArevE

96-Ball Fine-Pitch Ball Grid Array (FBGA), JEDEC MO-205, 5.5mm Wide Package Number BGA96A

Fairchild does not assume any responsibility for use of any circuitry described, no circuit patent licenses are implied and Fairchild reserves the right at any time without notice to change said circuitry and specifications.

LIFE SUPPORT POLICY

FAIRCHILD'S PRODUCTS ARE NOT AUTHORIZED FOR USE AS CRITICAL COMPONENTS IN LIFE SUPPORT DEVICES OR SYSTEMS WITHOUT THE EXPRESS WRITTEN APPROVAL OF THE PRESIDENT OF FAIRCHILD SEMICONDUCTOR CORPORATION. As used herein:

- 1. Life support devices or systems are devices or systems which, (a) are intended for surgical implant into the body, or (b) support or sustain life, and (c) whose failure to perform when properly used in accordance with instructions for use provided in the labeling, can be reasonably expected to result in a significant injury to the user.
- 2. A critical component in any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.

www.fairchildsemi.com